

In-Situ De-embedding (ISD)

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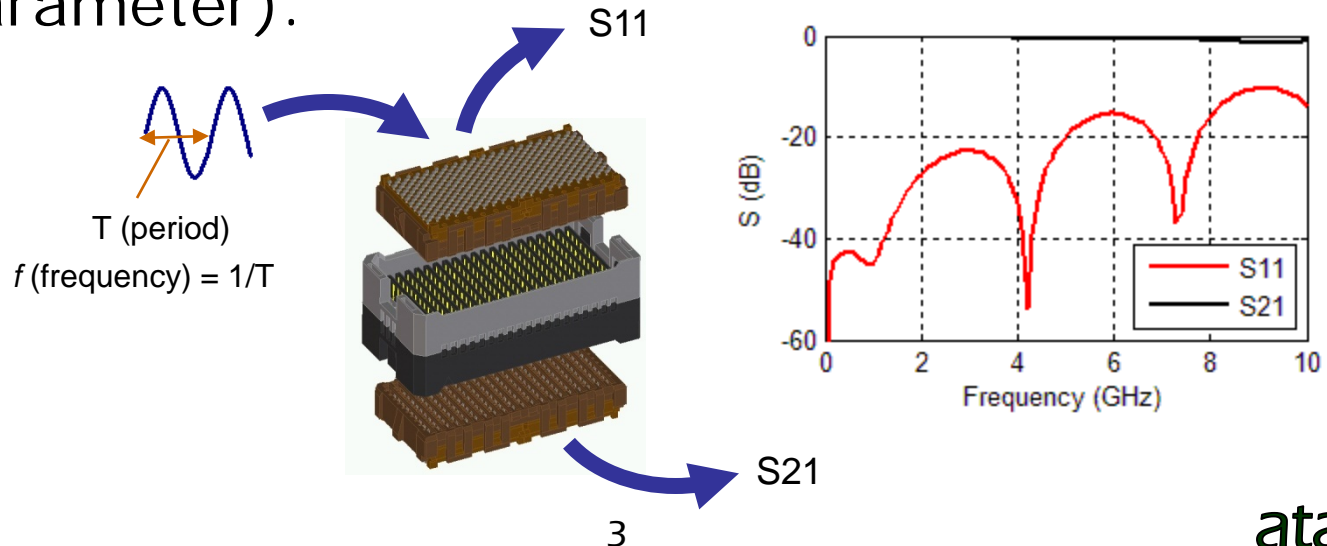
September 29, 2015

Outline

- What is causality
 - How to identify non-causal S parameter
 - Why does S parameter violate causality
- What is In-Situ De-embedding (ISD)
 - Why do other de-embedding methods give causality error
- How to use ISD to...
 - De-embed crosstalk by a single trace test coupon
 - De-embed long traces and extract a small DUT
 - Improve results for USB Type C compliance testing
- Comparison of ISD with TRL, AFR and simulation
- Mobile-apps-like SI tools: ISD, ADK and X2D2

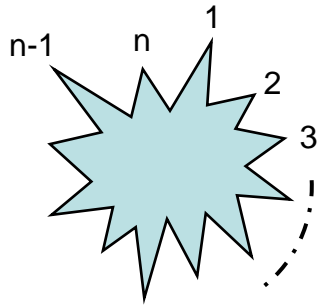
VNA and S parameter

- Vector network analyzer (VNA) is an equipment that launches a sinusoidal waveform into a structure, varies the period (or frequency) of waveform, and lets us observe the transmitted and reflected wave as “frequency-domain response”.
- Such frequency-domain response, when normalized to the incident wave, is called scattering parameter (or, S parameter).



What is S parameter

- For an n-port (or I/O) device, S parameter is an n x n matrix:



$$[S_{ij}]_{n \times n} = \begin{bmatrix} S_{11} & S_{12} & S_{13} & \dots & S_{1n} \\ S_{21} & S_{22} & S_{23} & \dots & S_{2n} \\ \vdots & \vdots & \vdots & \ddots & \vdots \\ S_{n1} & S_{n2} & S_{n3} & \dots & S_{nn} \end{bmatrix}$$

- S_{ij} is called the S parameter from Port j to Port i .
- S_{ij} has a unique property that its magnitude is less than or equal to 1 (or, 0 dB) for a passive device.

$$|S_{ij}| \leq 1$$

$$S_{ij} (dB) = 20 \times \log_{10} |S_{ij}| \leq 0 \text{ dB}$$

What is a Touchstone (.sNp) file

- S parameter at each frequency is expressed in Touchstone file format.

in GHz in dB and phase angle Reference impedance

```
! Total number of ports = 4
! Total number of frequency points = 800
# GHZ S DB R 50
0.025 -36.59296 48.77486 -41.40676 79.91354 -0.08648679 -6.544144 -49.50045 -105.618
      -41.39364 79.94686 -36.35592 51.52433 -49.4886 -105.5124 -0.09038406 -6.527076
      -0.08421237 -6.537903 -49.44814 -105.644 -36.0317 49.60022 -41.37105 79.91856
      -49.44393 -105.8186 -0.09834136 -6.542909 -41.36758 79.9318 -36.05645 48.98348
0.05 -32.22576 48.03161 -35.59394 74.15976 -0.1277169 -12.82876 -43.90183 -112.0995
      -35.58736 74.16304 -32.12694 50.92389 -43.90926 -112.0764 -0.132402 -12.7985
      -0.1242117 -12.82302 -43.89 -112.0248 -32.10987 50.3115 -35.56998 74.078
      -43.88424 -112.0517 -0.1381616 -12.80199 -35.56758 74.06782 -31.94136 50.49276
0.075 -29.88861 42.02766 -32.19713 68.06704 -0.1589249 -19.05252 -40.67476 -118.8188
      -32.19116 68.0941 -29.7086 45.41557 -40.63857 -118.837 -0.1635606 -19.01593
      -0.1603356 -19.0376 -40.63557 -118.8543 -29.89064 47.63852 -32.16917 67.94677
      -40.65711 -118.8021 -0.1737256 -19.02956 -32.16865 67.93389 -29.65444 46.15548
: : :
```

Frequency in GHz

S11, S12, ..., S44 in dB and phase angle

What is causality

cau·sal·i·ty

noun

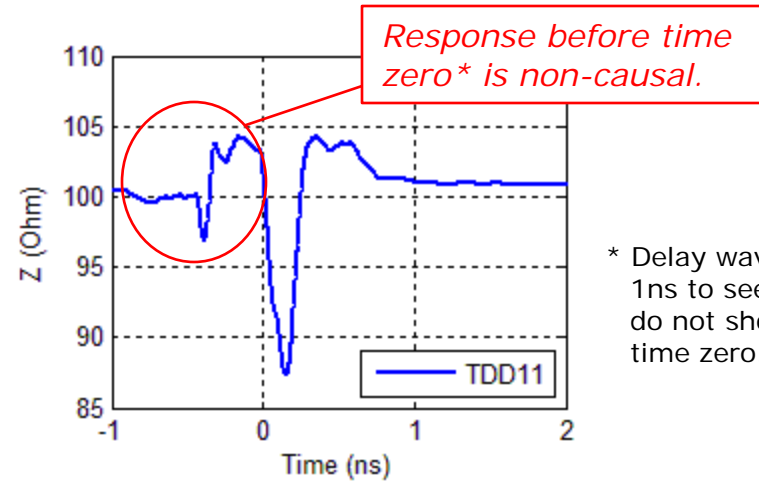
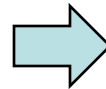
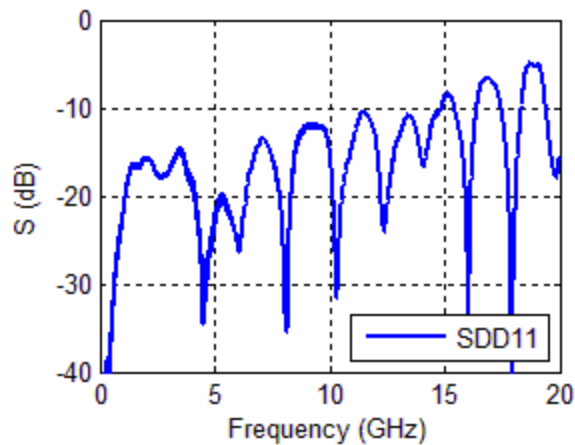
1. the relationship between cause and effect.
2. the principle that everything has a cause.

In other words:

Can not get something from nothing.

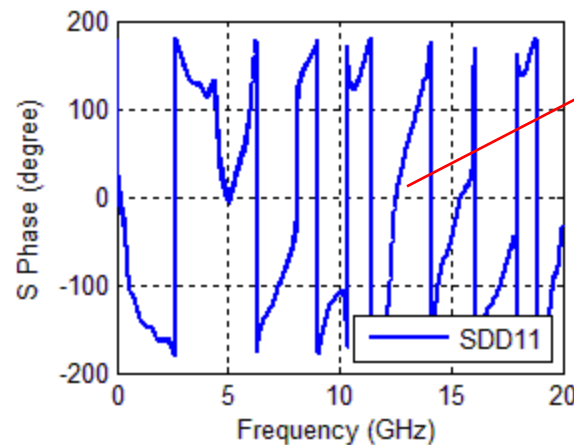
How to identify non-causal S parameter

- Convert S parameter into TDR/TDT.



* Delay waveform by 1ns to see if tools do not show before time zero.

- Check phase angle.



Counterclockwise phase angle is non-causal.

Why does S parameter violate causality

- Measurement error (**de-embedding**), simulation error (**material property**) and **finite bandwidth** of S parameter all contribute to non-causality.
- Kramers-Kronig relations require that the real and imaginary parts of an analytic function be related to each other through Hilbert transform:

$$\Psi(\omega) = \Psi_R(\omega) + j\Psi_I(\omega)$$

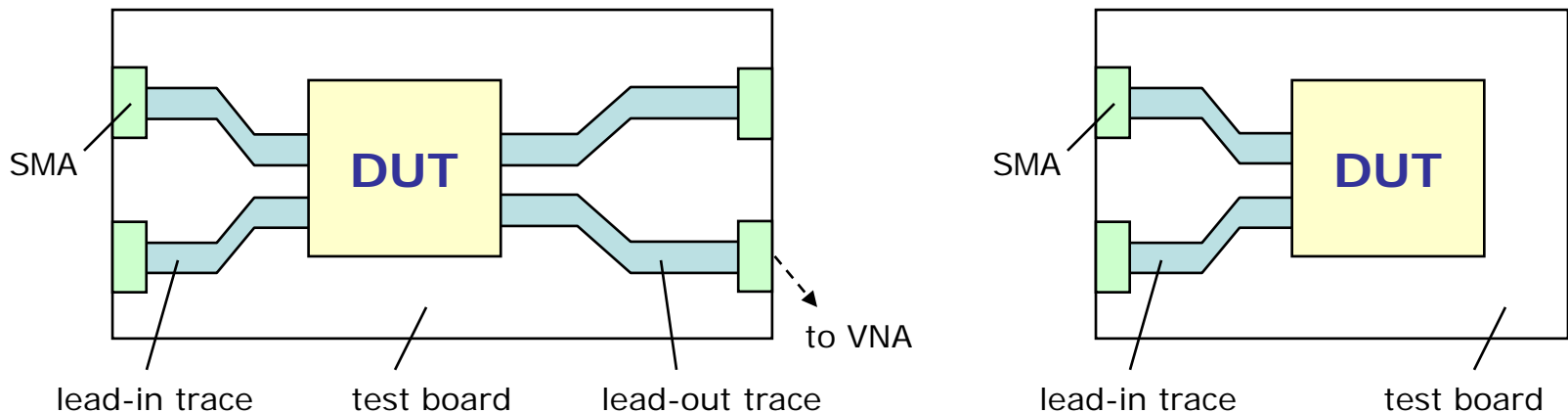
$$\Psi_R(\omega) = \frac{1}{\pi} P \int_{-\infty}^{\infty} \frac{\Psi_I(\omega')}{\omega' - \omega} d\omega'$$

$$\Psi_I(\omega) = -\frac{1}{\pi} P \int_{-\infty}^{\infty} \frac{\Psi_R(\omega')}{\omega' - \omega} d\omega'$$

In-Situ De-embedding (ISD) gives causal de-embedding and Advanced SI Design Kit (ADK) extracts causal material property and/or forces S parameter of finite bandwidth to give causal behavior of infinite bandwidth.

What is de-embedding

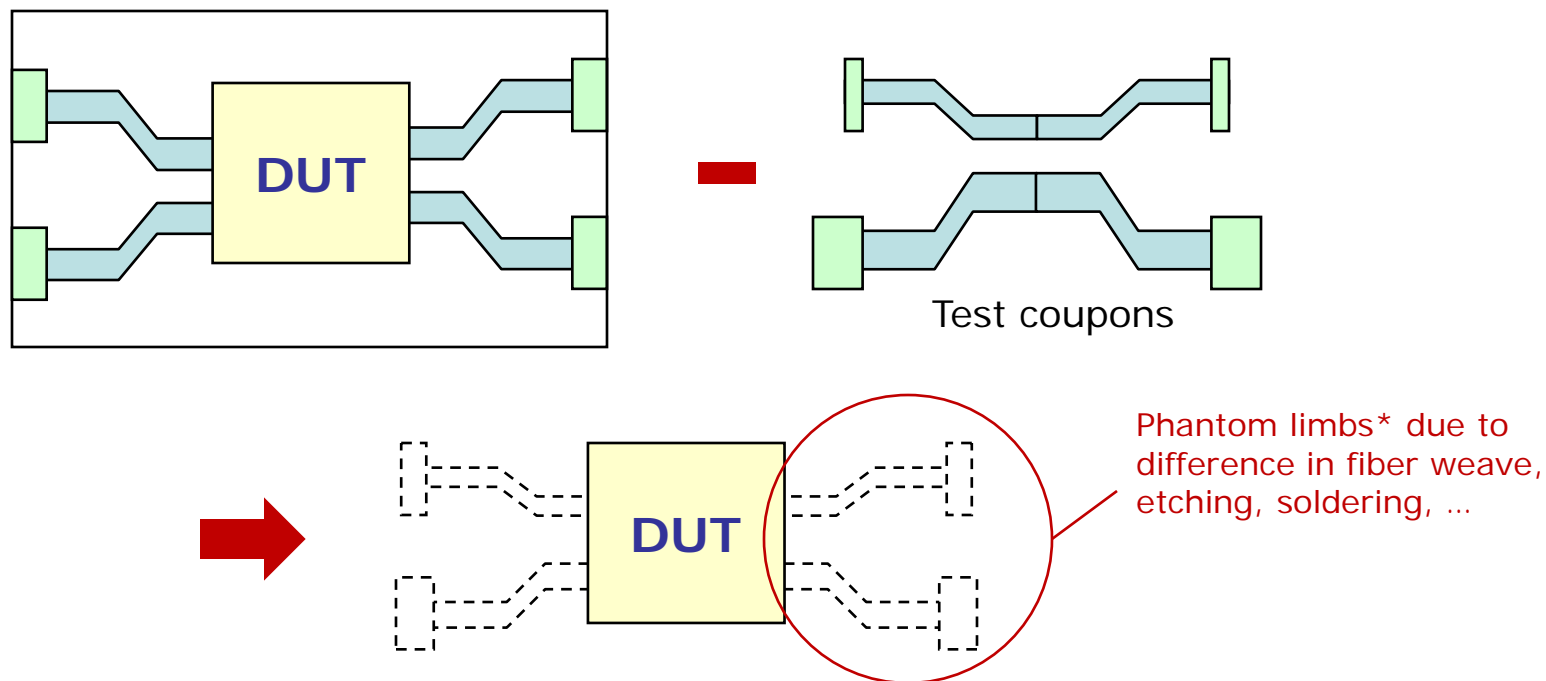
- To remove the effect of fixture (SMA connector + lead-in/out) and extract the S parameter of DUT (device under test).



- The lead-ins and lead-outs don't need to look the same.
- There may even be no lead-outs (e.g., package).

Why do most de-embedding tools give causality error

- Most tools use test coupons directly for de-embedding, so difference between actual fixture and test coupons gets piled up into DUT results.

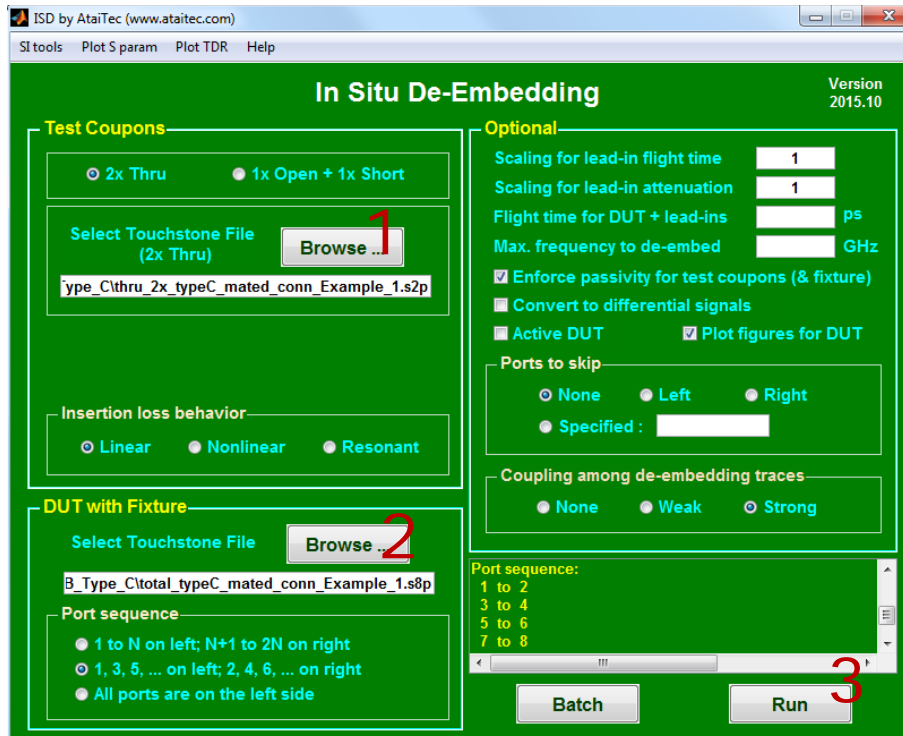


* <http://www.edn.com/electronics-blogs/test-voices/4438677/Software-tool-fixes-some-causality-violations> by Eric Bogatin

What is In-Situ De-embedding (ISD)

- Use “2x thru” or “1x open + 1x short” as reference and de-embed fixture’s actual impedence through optimization.

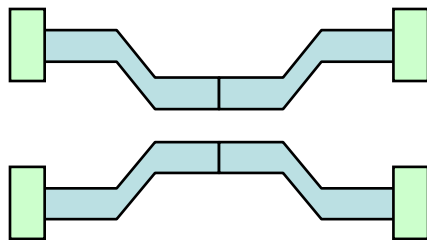
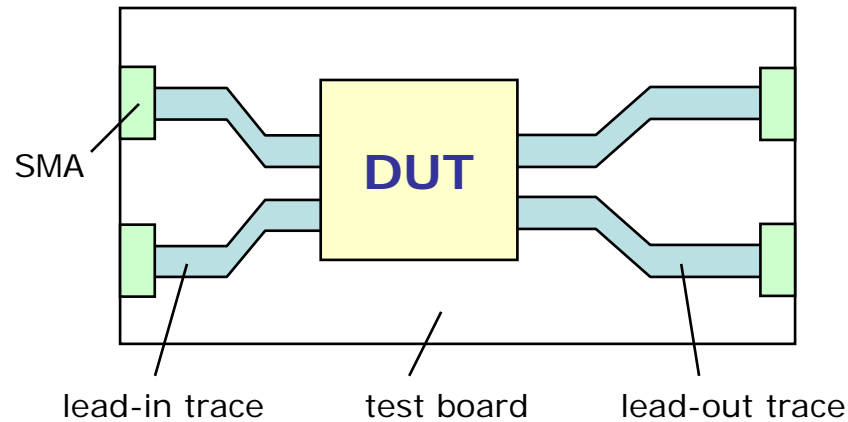
In Situ



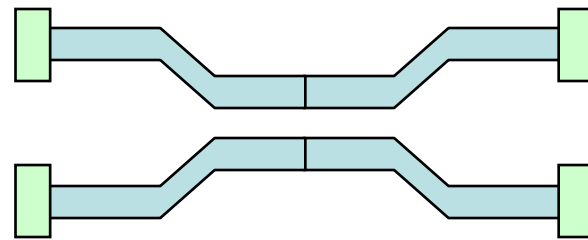
- Mobile-Apps-like SI software as easy to use as 1-2-3.*
- Causal by construction.*

What is "2x thru"

- "2x thru" is 2x lead-ins or lead-outs.



2x thru for lead-ins

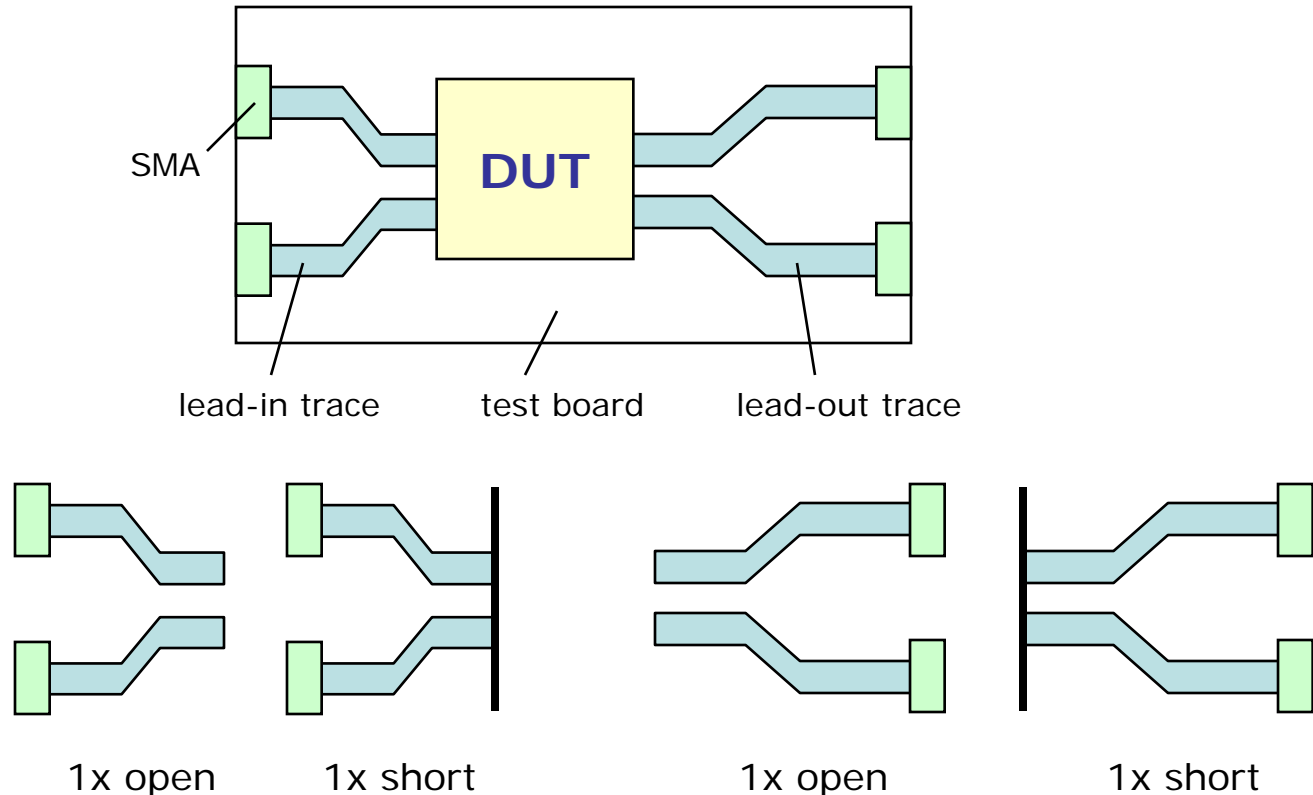


2x thru for lead-outs

2 sets of "2x thru" are required for asymmetric fixture.

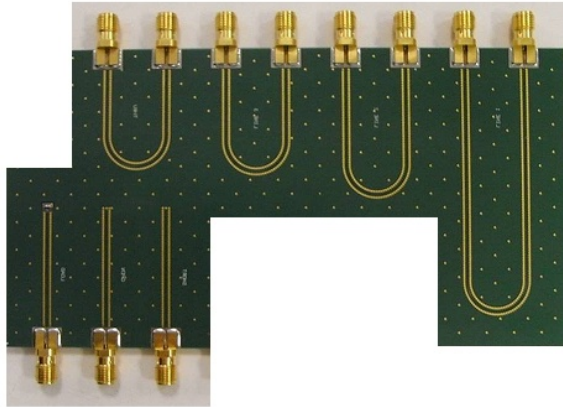
What is "1x open + 1x short"

- "1x open + 1x short" is useful when "2x thru" is not possible (e.g., connector vias, package, ...).



Why ISD is more accurate and saves \$\$\$

TRL calibration board



- More board space - Multiple test coupons are required.
- Test coupons are used directly for de-embedding.
- All difference between calibration and actual DUT boards gets piled up into DUT results.
- Expensive SMAs, board materials (Roger) and tight-etching-tolerance are required.
 - Impossible to guarantee all SMAs and traces are identical (consider weaves, etching, ...)
- Time-consuming manual calibration is required.
 - Reference plane is in front of DUT.

ISD test coupon



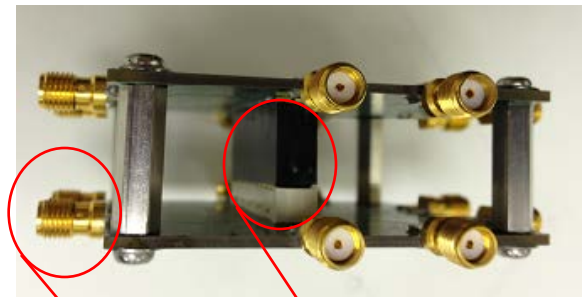
- Only one 2x thru test coupon is needed.
- Test coupon is used only for reference, not for direct de-embedding.
- Actual DUT board impedance is de-embedded.
- Inexpensive SMAs, board materials (FR4) and loose-etching-tolerance can be used.
- ECal can be used for fast SOLT calibration.
 - Reference plane is in front of SMA.
 - De-embedding is made easy as 1-2-3 with only two input files: 2x thru and DUT board (SMA-to-SMA) Touchstone files.
 - More information: Both de-embedding and DUT files are provided as outputs.

* TRL = Thru-Reflect-Line

Example 1: Mezzanine connector

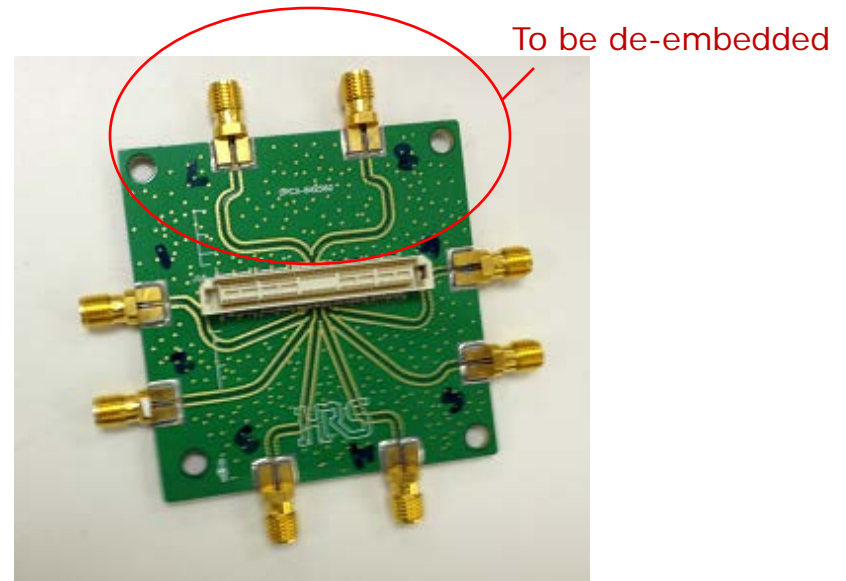
ISD vs. TRL

- In this example, we will use ISD and TRL to extract a mezzanine connector and compare their results.



SMA

Mezzanine
connector
(DUT)



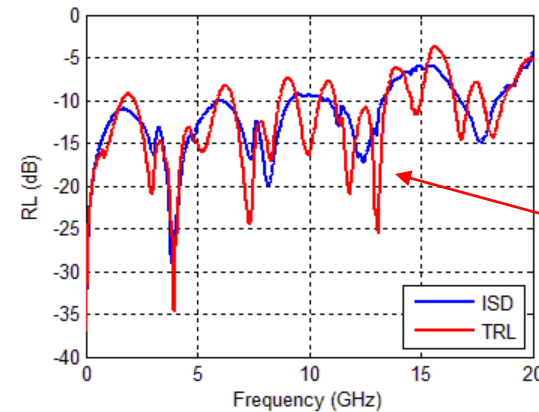
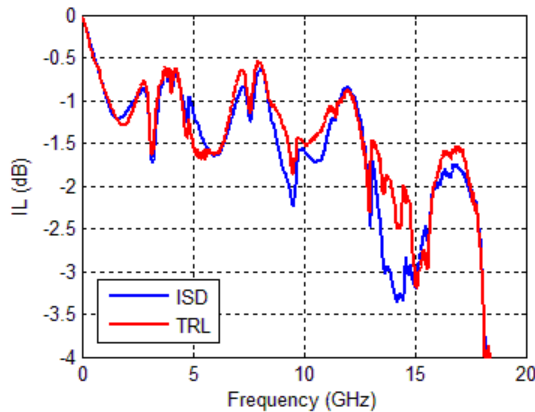
To be de-embedded

*Courtesy of Hirose Electric

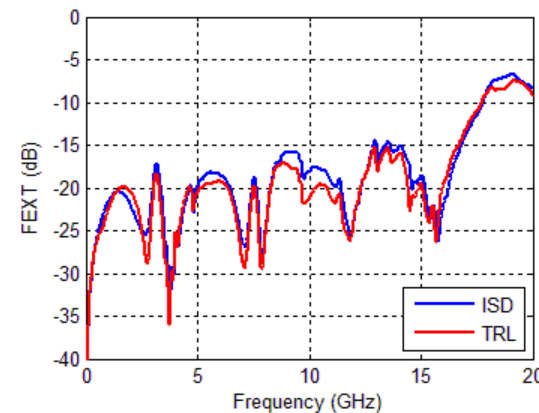
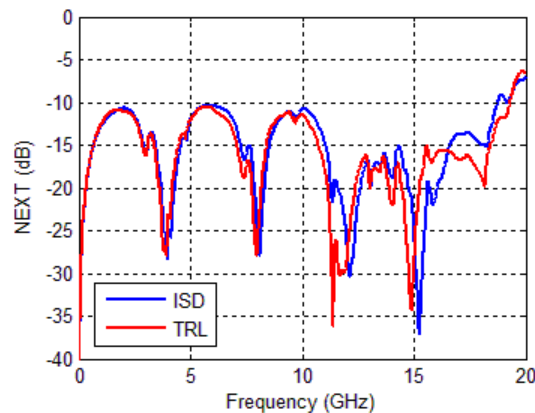
DUT results after ISD and TRL

Which one is more accurate?

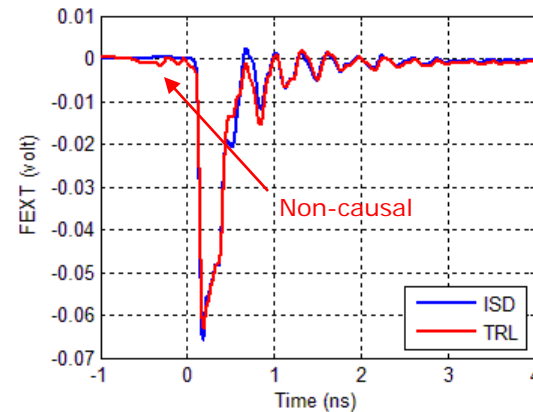
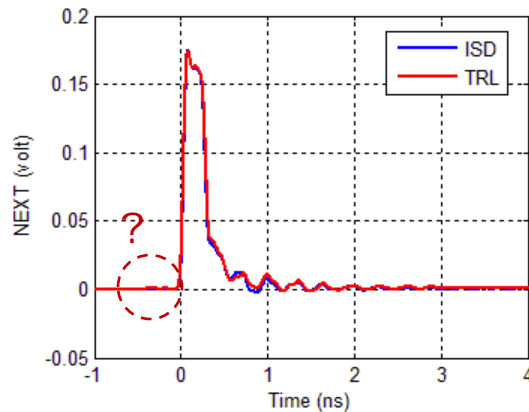
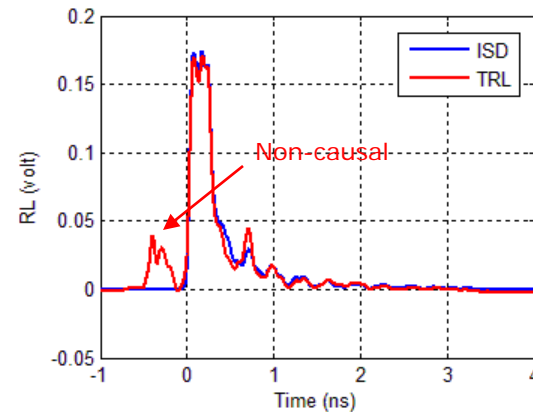
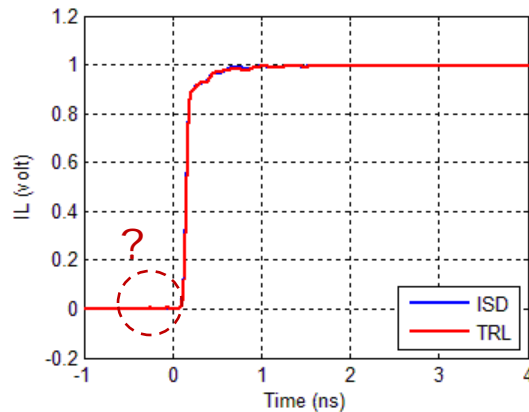
- TRL gives too many ripples in return loss (RL) for such a small DUT.



Non-causal ripples



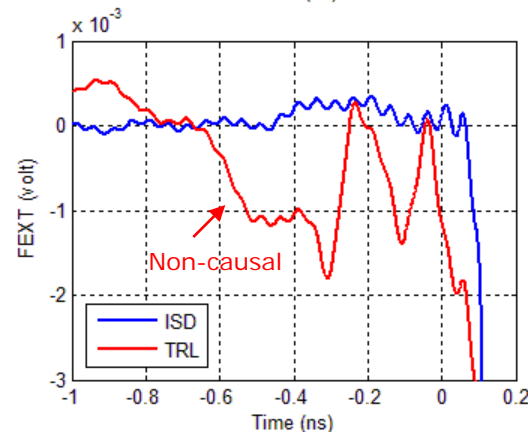
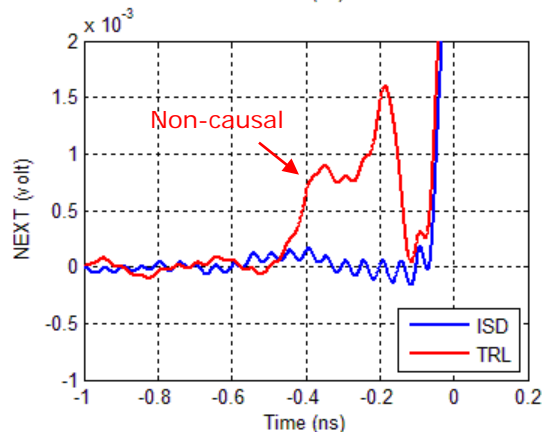
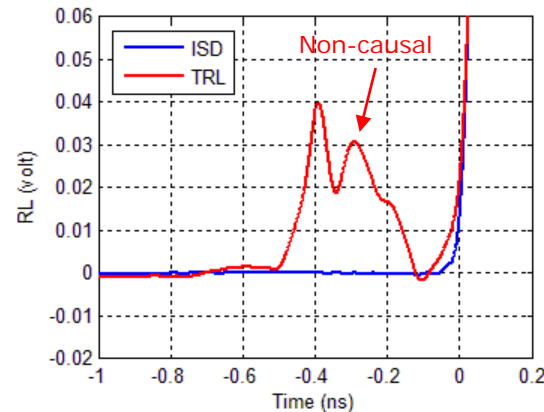
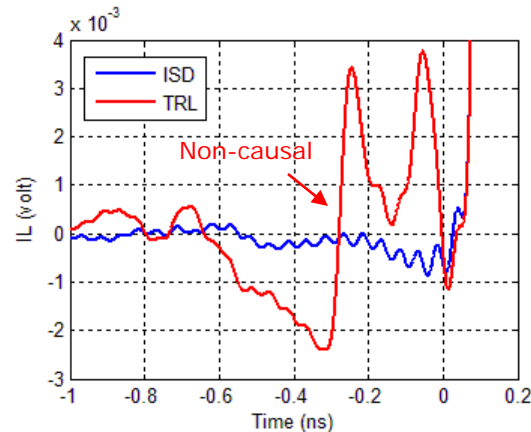
Converting S parameter into TDR/TDT shows non-causality in TRL results



Rise time = 40ps (20/80)

Zoom-in shows non-causal TRL results in all IL, RL, NEXT and FEXT

- TRL causes time-domain errors of 0.38% (IL), 25.81% (RL), 1.05% (NEXT) and 2.86% (FEXT) in this case*.

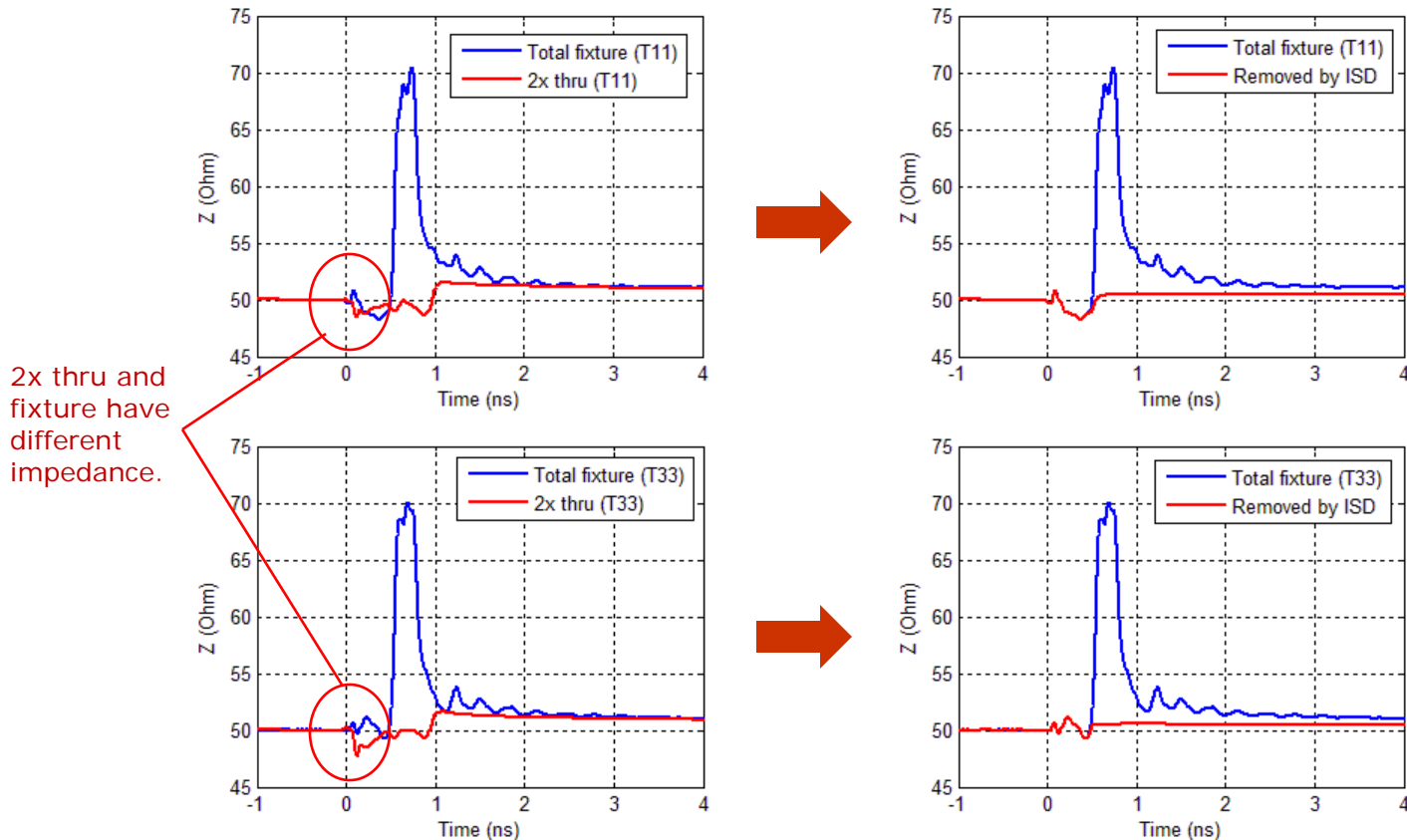


* The percentage is larger with single-bit response and/or faster rise time.

Rise time = 40ps (20/80)

How did ISD do it?

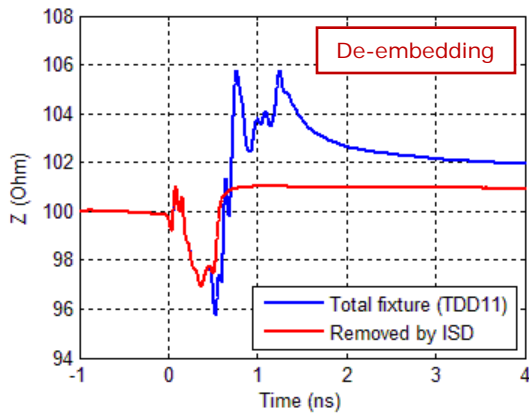
- Through optimization, ISD de-embeds fixture's impedance exactly, independent of 2x thru's impedance.



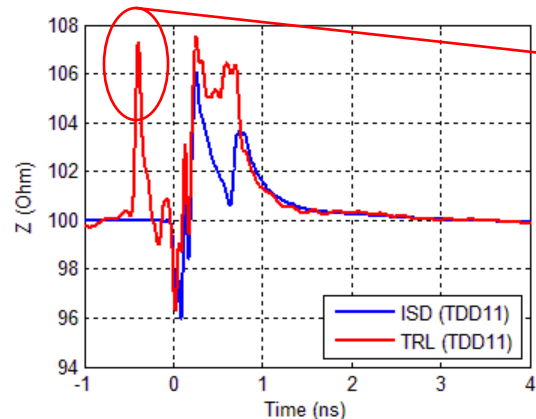
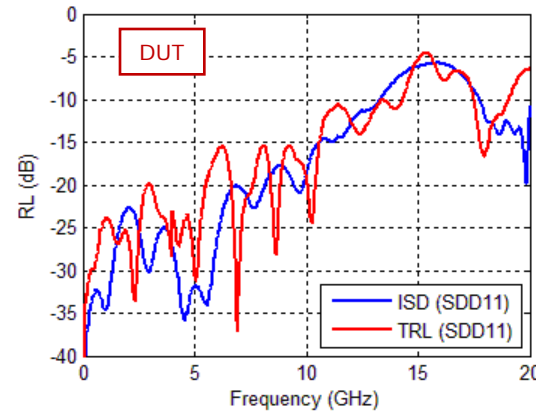
Rise time = 40ps (20/80)

TRL can give huge error in SDD11 even with small impedance variation*

- ISD is able to de-embed fixture's differential impedance with only a single-trace 2x thru.



* The impedance variation between 2x thru and fixture is less than 5%. (See previous slide.)



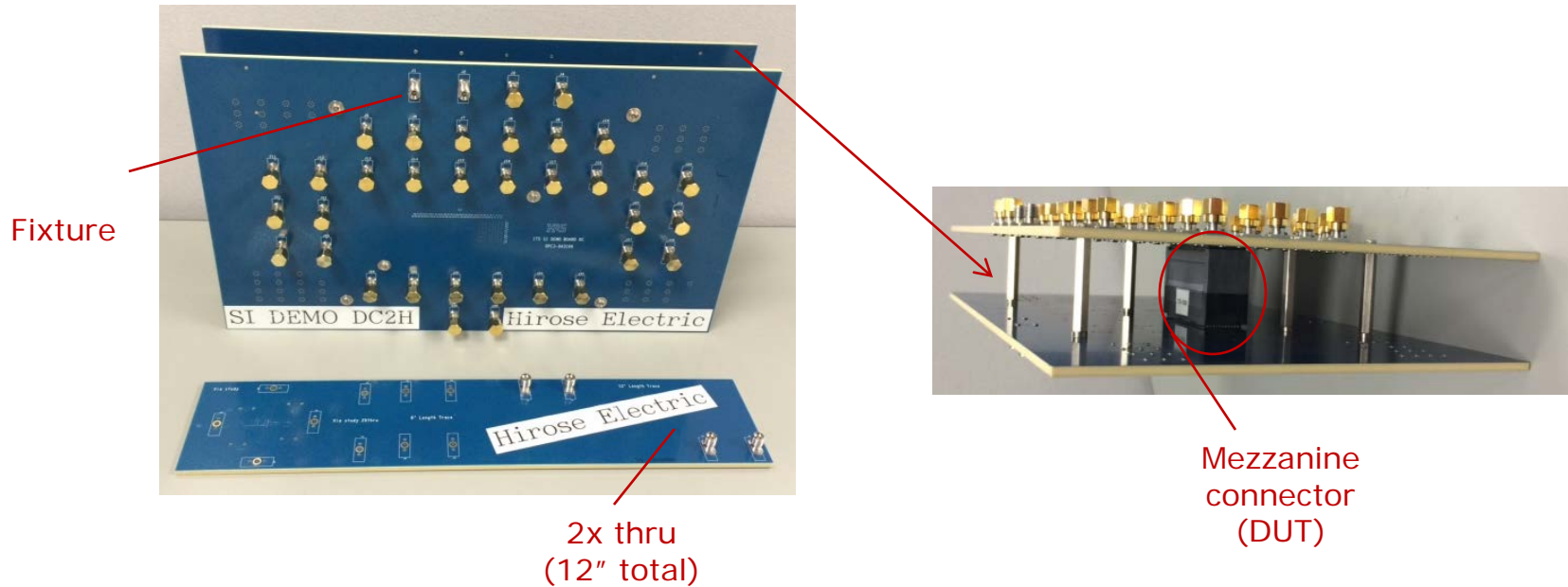
TRL gives more than 100% error due to causality violation.

Rise time = 40ps (20/80)

Example 2: Mezzanine connector

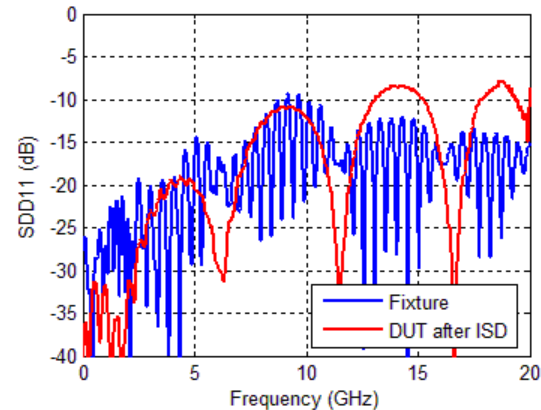
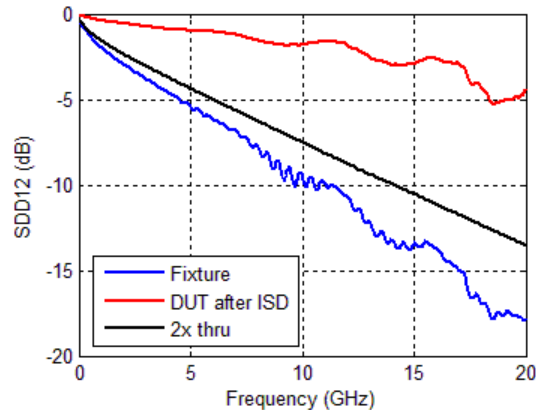
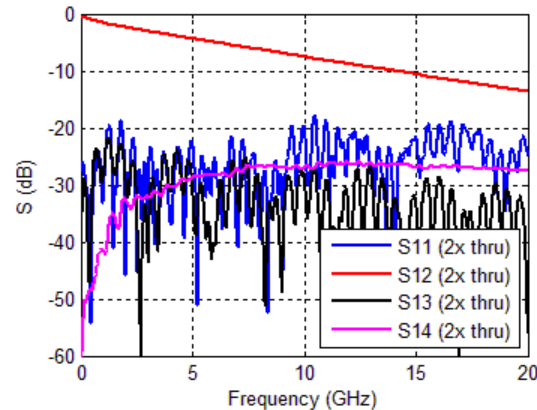
Extracting DUT from a large board

- TRL is impractical for de-embedding large and coupled lead-ins/outs.



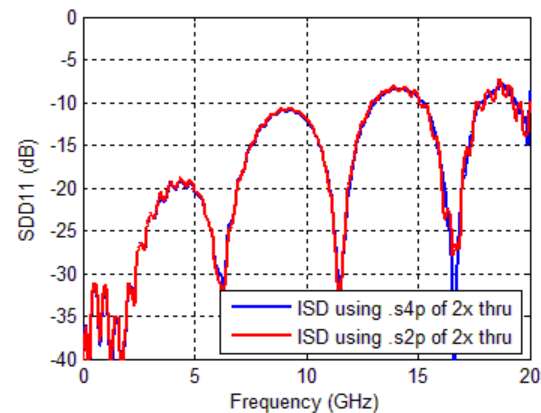
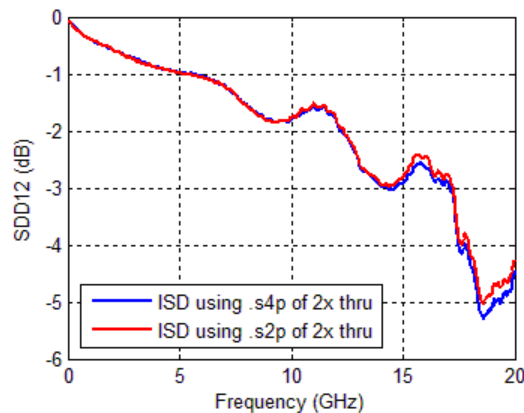
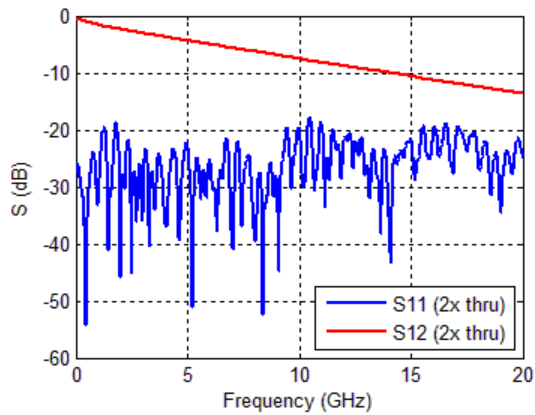
ISD can use a .s4p file of 2x thru for de-embedding

- TRL would have required many long and coupled traces.



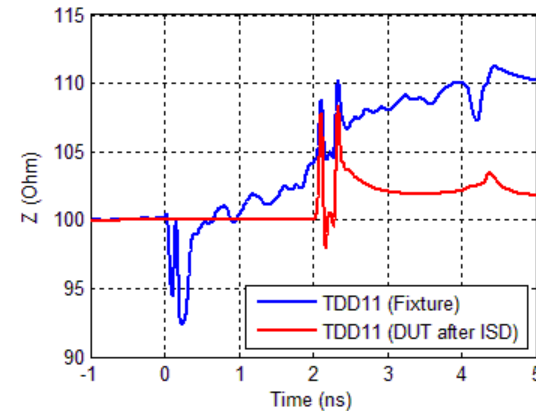
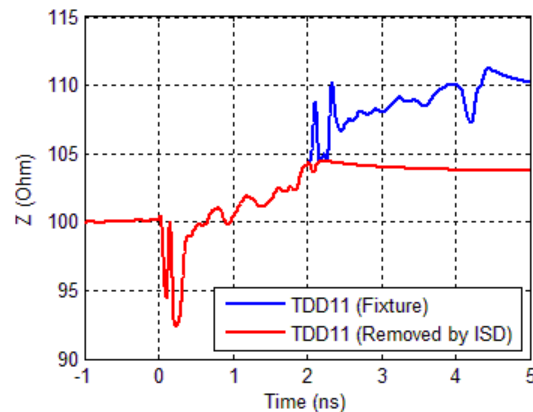
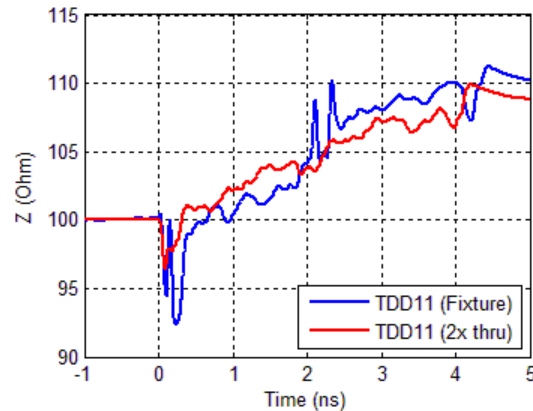
ISD can even use a .s2p file of 2x thru to de-embed crosstalk...

- And the results are similar!



ISD allows a large demo board to double as a characterization board

- ISD de-embeds fixture's impedance regardless of 2x thru's impedance.

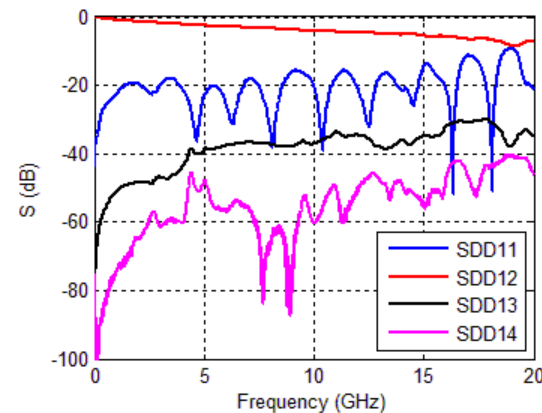
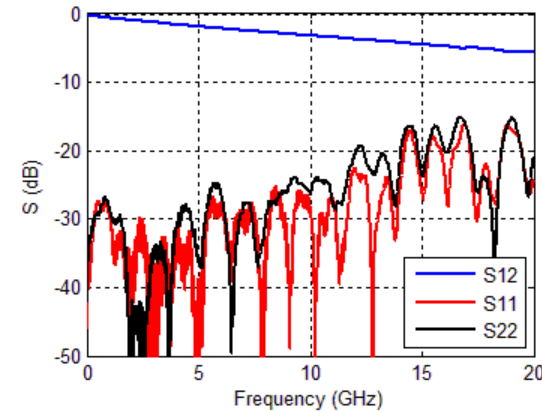
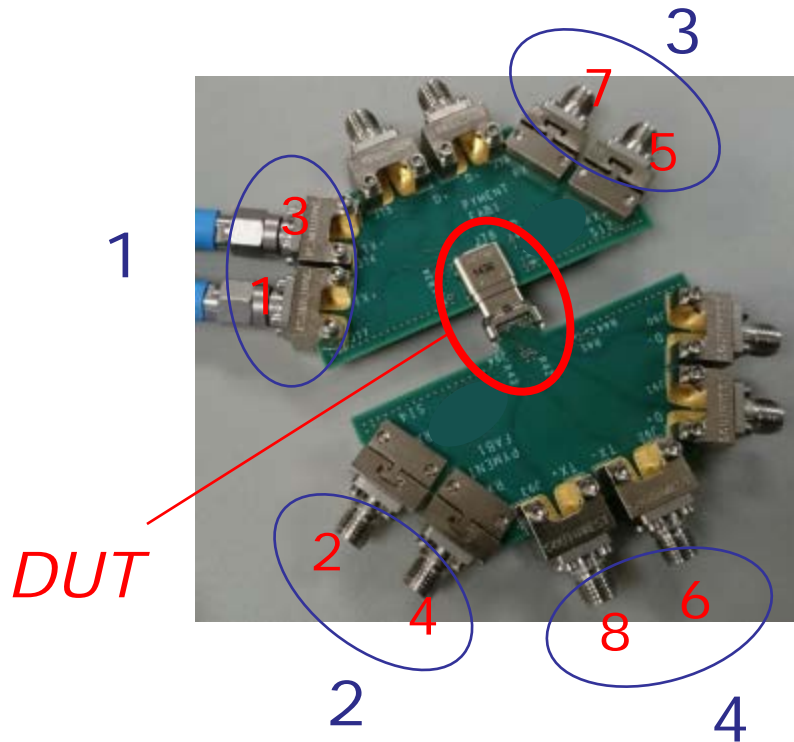


Rise time = 40ps (20/80)

Example 3: USB type C mated connector

ISD vs. AFR

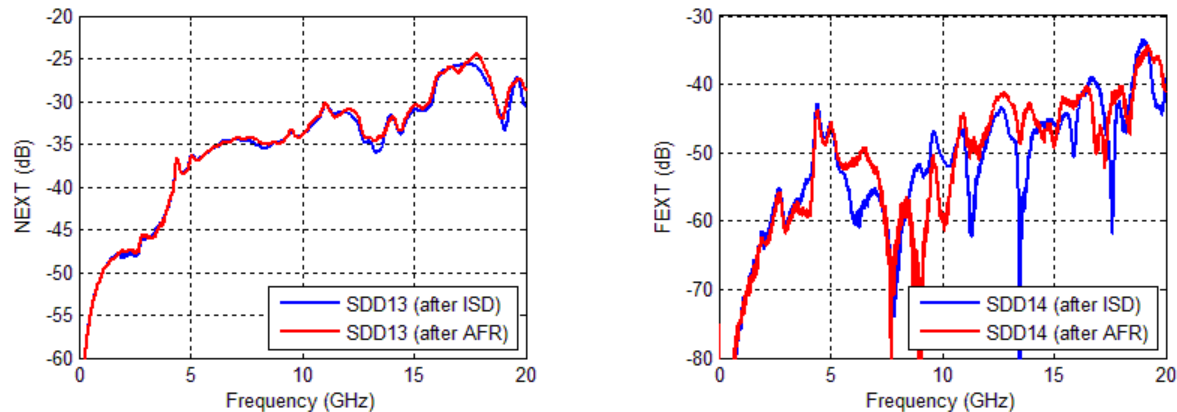
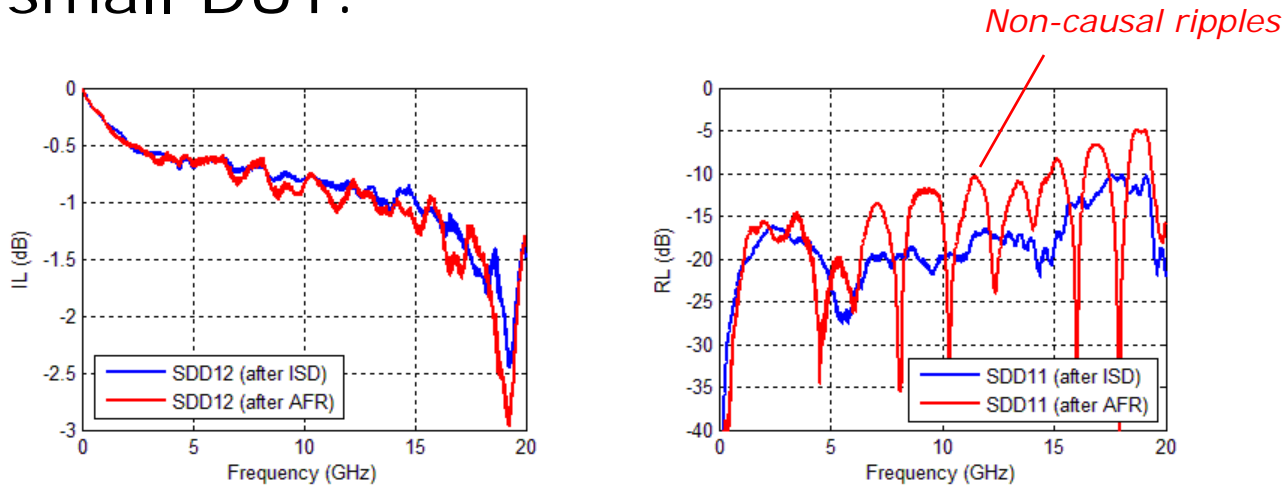
- Good de-embedding is crucial for meeting compliance spec.



DUT results after ISD and AFR

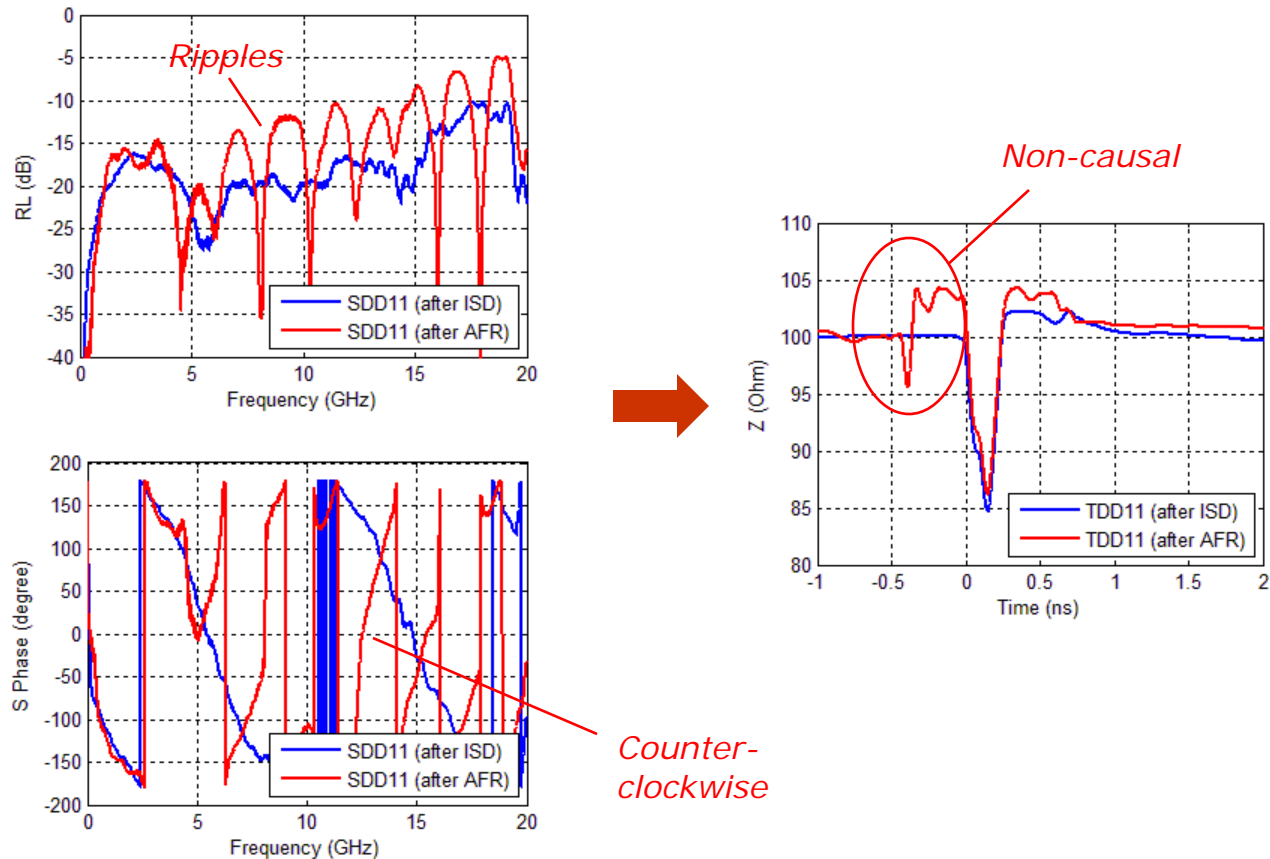
Which one is more accurate?

- AFR gives too many ripples in return loss (RL) for such a small DUT.



Converting S parameter into TDR/TDT shows non-causality in AFR results

- Counter-clockwise phase angle is another indication of non-causality.

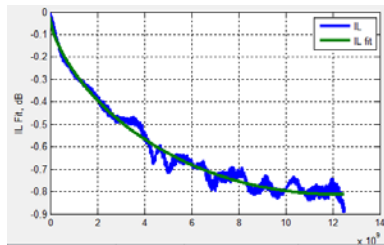


De-embedding affects pass or fail of compliance spec.

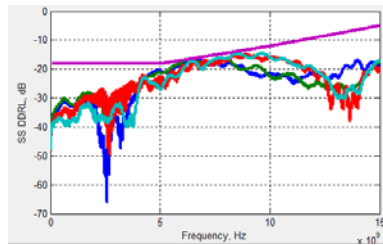
- ISD improves IMR and IRL (from compliance tool).

ISD

| | Value (Pass/Fail) |
|---------------|----------------------|
| ILfit@2.5GHz | -0.4 |
| ILfit@5.0 GHz | -0.6 |
| ILfit@10.0GHz | -0.8 |
| IMR | -45.1 |
| IRL | -23.2 |
| INEXT | -41.5 |
| IFEXT | -49.2 |
| SCD12/SCD21 | -23 |



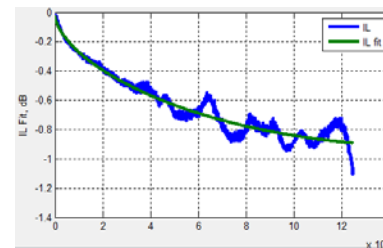
IL



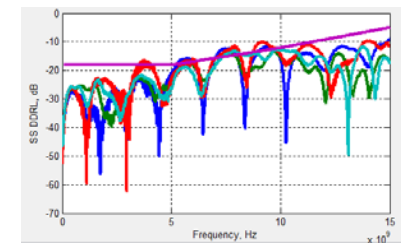
RL

AFR

| | Value (Pass/Fail) | Spec |
|---------------|----------------------|------|
| ILfit@2.5GHz | -0.4 | -0.6 |
| ILfit@5.0 GHz | -0.6 | -0.8 |
| ILfit@10.0GHz | -0.9 | -1.0 |
| IMR | -43.7 | -40 |
| IRL | -20.8 | -18 |
| INEXT | -41.5 | -44 |
| IFEXT | -49.3 | -44 |
| SCD12/SCD21 | -23.2 | |



IL

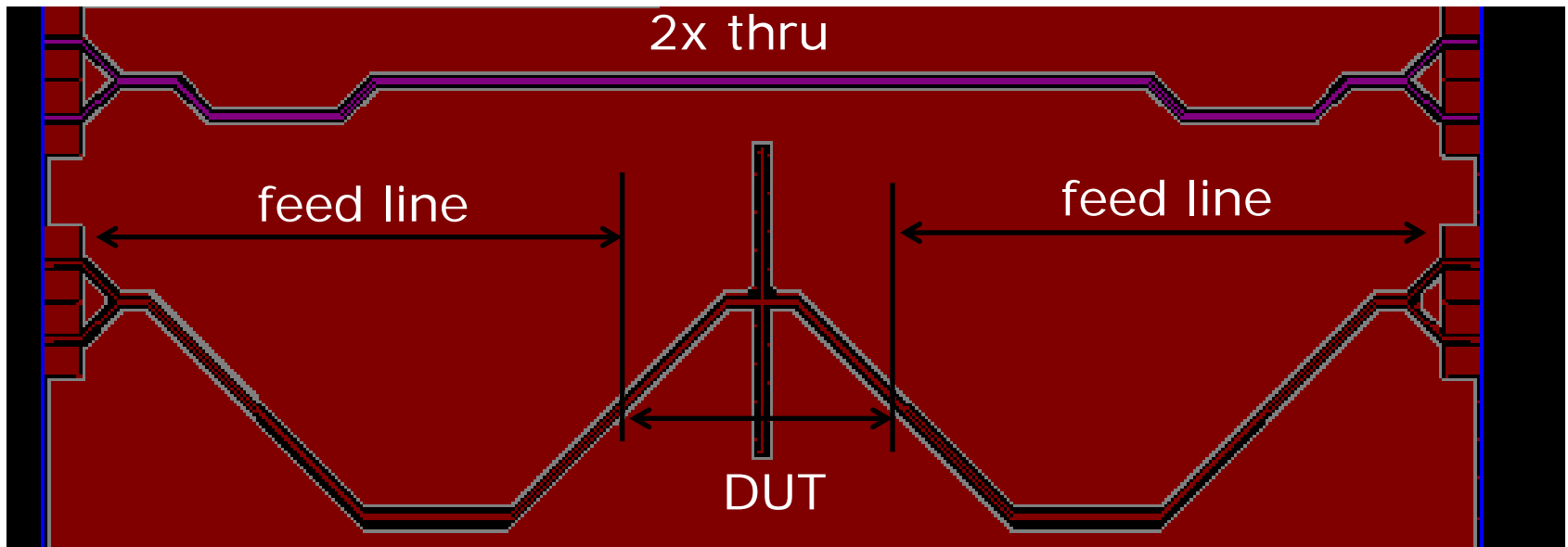


RL

Example 4: Resonator

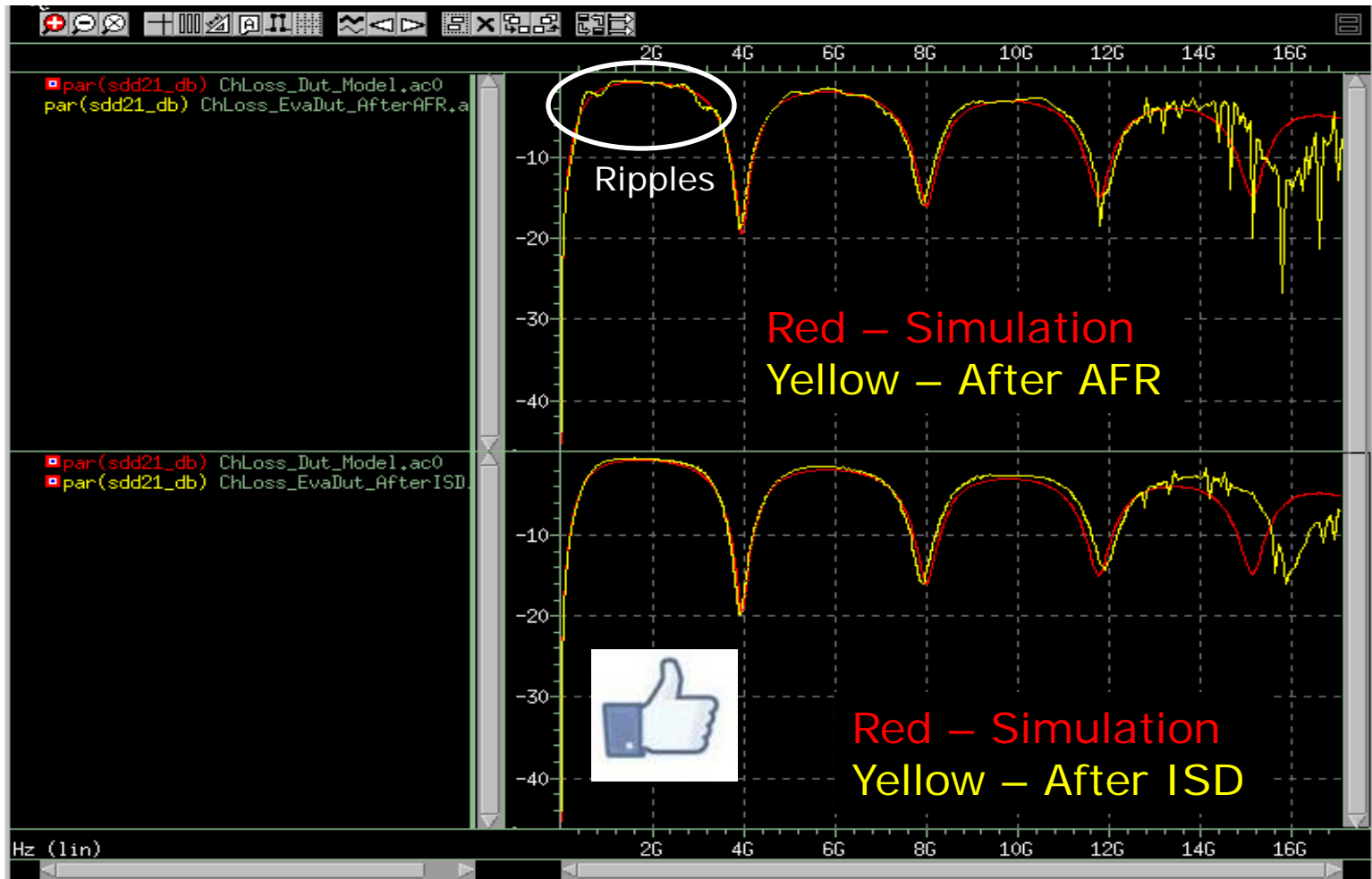
ISD vs. AFR vs. simulation

- Good de-embedding is crucial for design verification (i.e., correlation) and improvement.



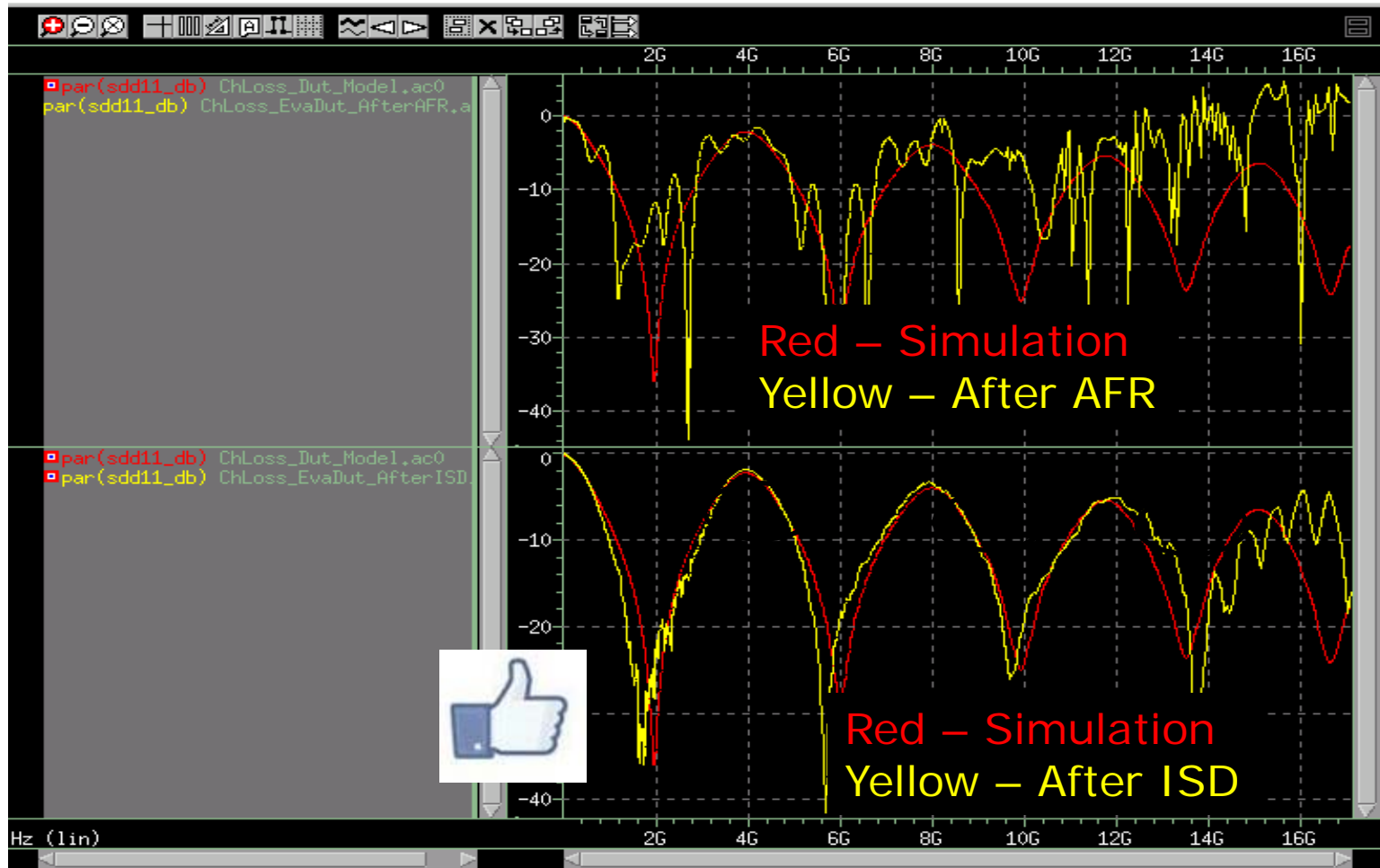
SDD21

ISD correlates with simulation better



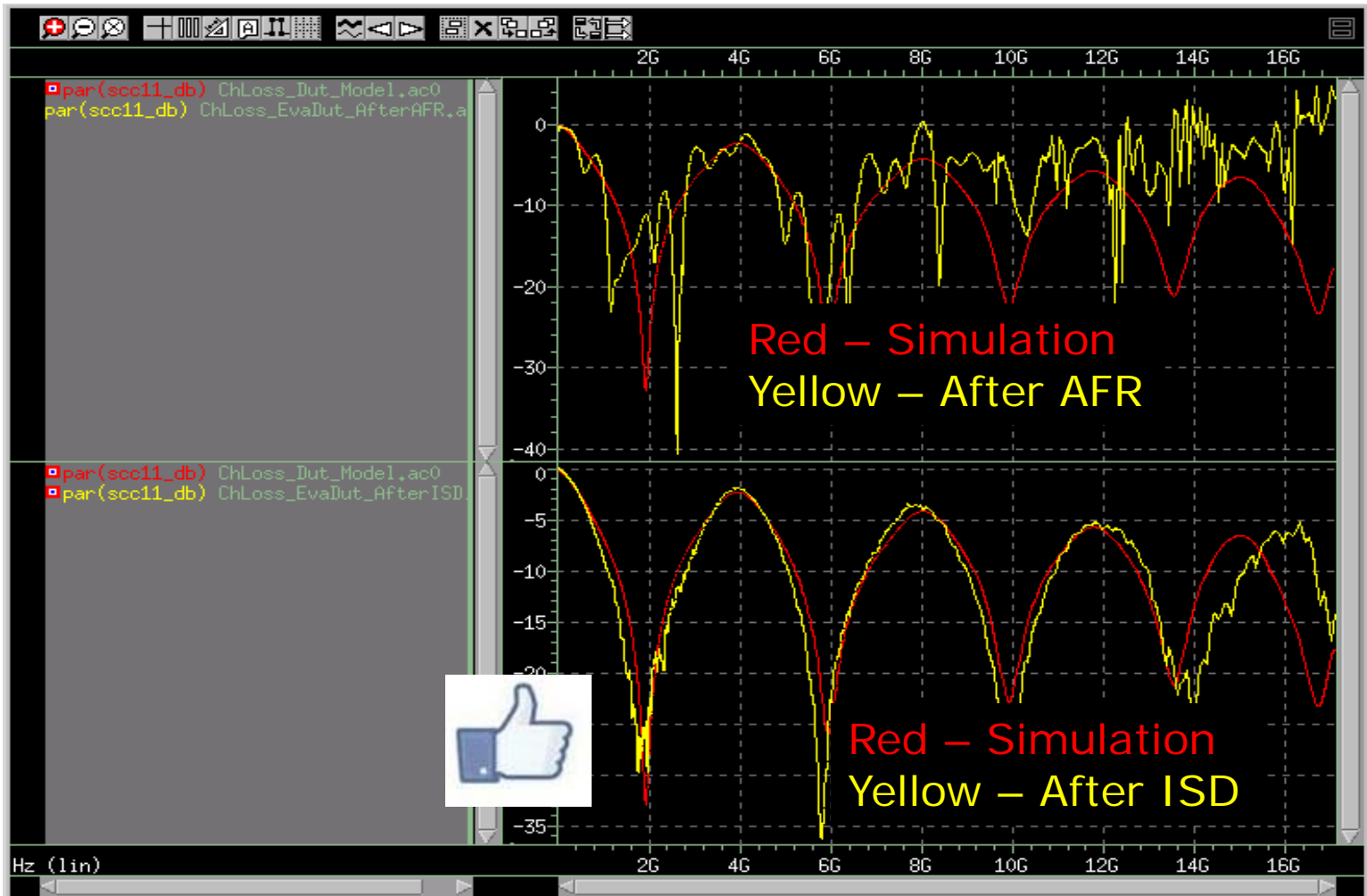
SDD11

ISD correlates with simulation much better



SCC11

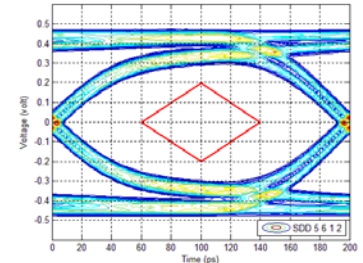
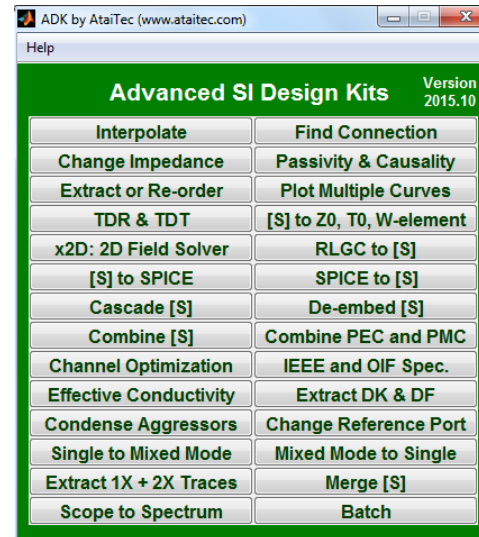
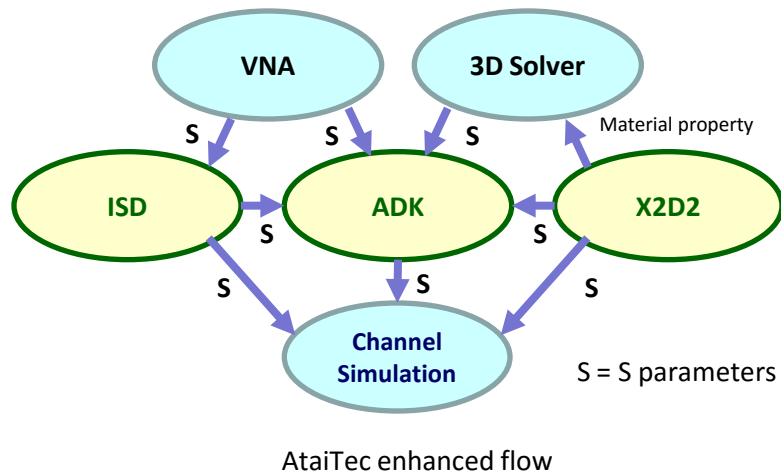
ISD correlates with simulation much better



ADK and X2D2

Mobile-apps-like SI tools

- ADK is a collection of many SI programs to convert S parameter into TDR/TDT, SPICE model or eye diagrams, compare with industry spec. (ICR, ICN, ...) and extract DK, DF and roughness, ...
- X2D2 models the effect of surface roughness on all IL, RL, NEXT and FEXT by effective conductivity.



Summary

- In-Situ De-embedding (ISD) solves the causality problem commonly encountered in de-embedding.
- ISD is causal by construction and it can...
 - give more accurate DUT results,
 - de-embed crosstalk using a single-trace coupon,
 - de-embed long traces and extract a small DUT,
 - give better DUT results for compliance testing,
 - correlate with simulation better and make design refinement possible.
- Mobile-apps-like ISD is easy to use and it helps save \$\$\$ from board material, correlation and design cycle time, ...